

IXFN82N60P Datasheet



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DiGi Electronics Part Number IXFN82N60P-DG

Manufacturer IXYS

Manufacturer Product Number IXFN82N60P

Description MOSFET N-CH 600V 72A SOT-227B

Detailed Description N-Channel 600 V 72A (Tc) 1040W (Tc) Chassis Moun

t SOT-227B



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXFN82N60P	IXYS
Series:	Product Status:
HiPerFET™, Polar	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
600 V	72A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	75mOhm @ 41A, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
5V @ 8mA	240 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±30V	23000 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	1040W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Chassis Mount
Supplier Device Package:	Package / Case:
SOT-227B	SOT-227-4, miniBLOC
Base Product Number:	
IXFN82	

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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